

Electrical Characteristics, Q1, MMBT4403 PNP Transistor Element

@T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)				-			
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40		V	$I_{\rm C}$ = -100µA, $I_{\rm E}$ = 0		
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	_	V	I _C = -1.0mA, I _B = 0		
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	—	V	$I_E = -100 \mu A$, $I_C = 0$		
Collector Cutoff Current	ICEX	_	-100	nA	V_{CE} = -35V, $V_{EB(OFF)}$ = -0.4V		
Base Cutoff Current	I _{BL}	_	-100	nA	V_{CE} = -35V, $V_{EB(OFF)}$ = -0.4V		
ON CHARACTERISTICS (Note 5)					· · · ·		
DC Current Gain	hfe	30 60 100 100 20	 300 	_	$\begin{split} I_{C} &= -100 \mu A, V_{CE} &= -1.0V \\ I_{C} &= -1.0mA, V_{CE} &= -1.0V \\ I_{C} &= -10mA, V_{CE} &= -1.0V \\ I_{C} &= -150mA, V_{CE} &= -2.0V \\ I_{C} &= -500mA, V_{CE} &= -2.0V \end{split}$		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.40 -0.75	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA		
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.75	-0.95 -1.30	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA		
SMALL SIGNAL CHARACTERISTICS			•				
Output Capacitance	C _{cb}	_	8.5	pF	V _{CB} = -10V, f = 1.0MHz, I _E = 0		
Input Capacitance	Ceb	_	30	pF	V _{EB} = -0.5V, f = 1.0MHz, I _C = 0		
Input Impedance	h _{ie}	1.5	15	kΩ			
Voltage Feedback Ratio	h _{re}	0.1	8.0	x 10⁻⁴	$V_{CE} = -10V, I_{C} = -1.0mA,$		
Small Signal Current Gain	h _{fe}	60	500		f = 1.0kHz		
Output Admittance	h _{oe}	1.0	100	μS			
Current Gain-Bandwidth Product	f _T	200		MHz	V _{CE} = -10V, I _C = -20mA, f = 100MHz		
SWITCHING CHARACTERISTICS	· · · · · · · · · · · · · · · · · · ·		•				
Delay Time	td		15	ns	V _{CC} = -30V, I _C = -150mA,		
Rise Time	tr	_	20	ns	V _{BE(off)} = -2.0V, I _{B1} = -15mA		
Storage Time	t _s		225	ns	V _{CC} = -30V, I _C = -150mA,		
Fall Time	t _f	_	30	ns	$I_{B1} = I_{B2} = -15mA$		

Electrical Characteristics, Q2, 2N7002 N-Channel MOSFET Element

 $@T_A = 25^{\circ}C$ unless otherwise specified

Characteris	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)							·	
Drain-Source Breakdown Voltage		BV _{DSS}	60	70	—	V	$V_{GS} = 0V, I_D = 10 \mu A$	
Zero Gate Voltage Drain Current	@ T _C = 25°C @ T _C = 125°C	I _{DSS}	_	_	1.0 500	μA	V _{DS} = 60V, V _{GS} = 0V	
Gate-Body Leakage		I _{GSS}	_	_	±10	nA	V_{GS} = ±20V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 5)		•					·	
Gate Threshold Voltage		V _{GS(th)}	1.0	—	2.0	V	V _{DS} = V _{GS} , I _D =-250μA	
Static Drain-Source On-Resistance	R _{DS} (ON)	_	3.2 4.4	7.5 13.5	Ω	V _{GS} = 5.0V, I _D = 0.05A V _{GS} = 10V, I _D = 0.5A		
On-State Drain Current		I _{D(ON)}	0.5	1.0	—	Α	V _{GS} = 10V, V _{DS} = 7.5V	
Forward Transconductance		g Fs	80	_	_	mS	V _{DS} =10V, I _D = 0.2A	
DYNAMIC CHARACTERISTICS							·	
Input Capacitance	Ciss		22	50	pF			
Output Capacitance				11	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}		2.0	5.0	pF	1 - 1.00012		
SWITCHING CHARACTERISTICS								
Turn-On Delay Time		t _{D(ON)}	—	7.0	20	ns	V _{DD} = 30V, I _D = 0.2A,	
Turn-Off Delay Time	t _{D(OFF)}		11	20	ns	$R_L = 150\Omega$, $V_{GEN} = 10V$, $R_{GEN} = 259$		

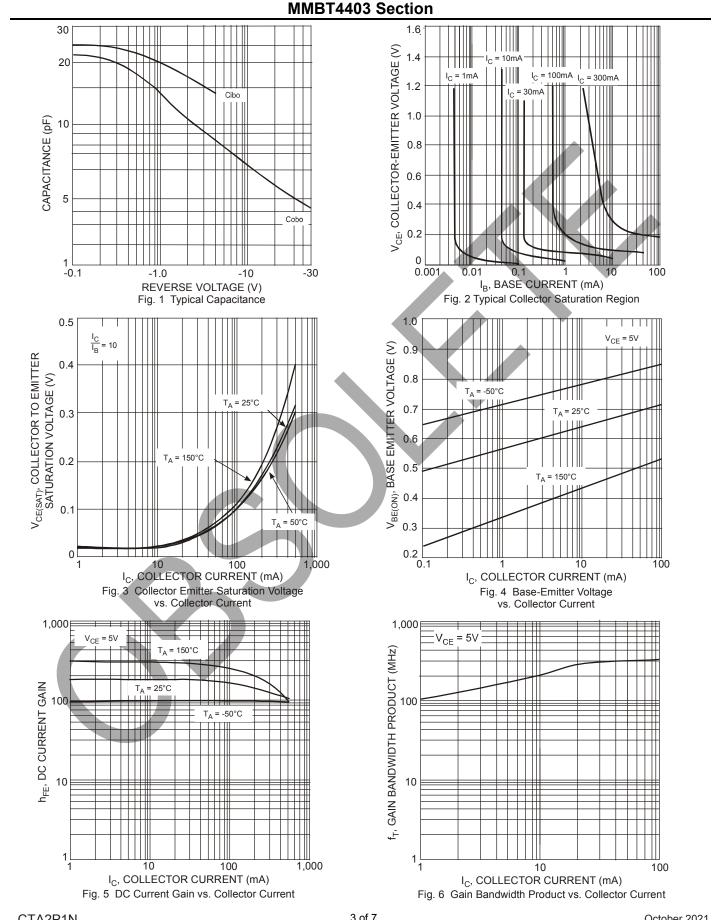
Notes: 5. Short duration pulse test used to minimize self-heating effect.



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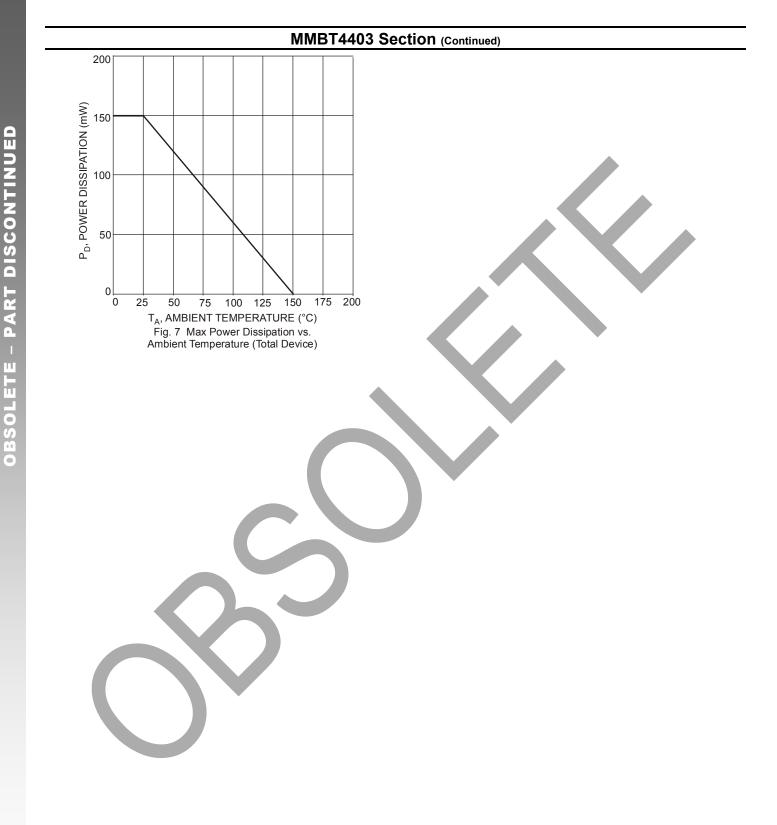
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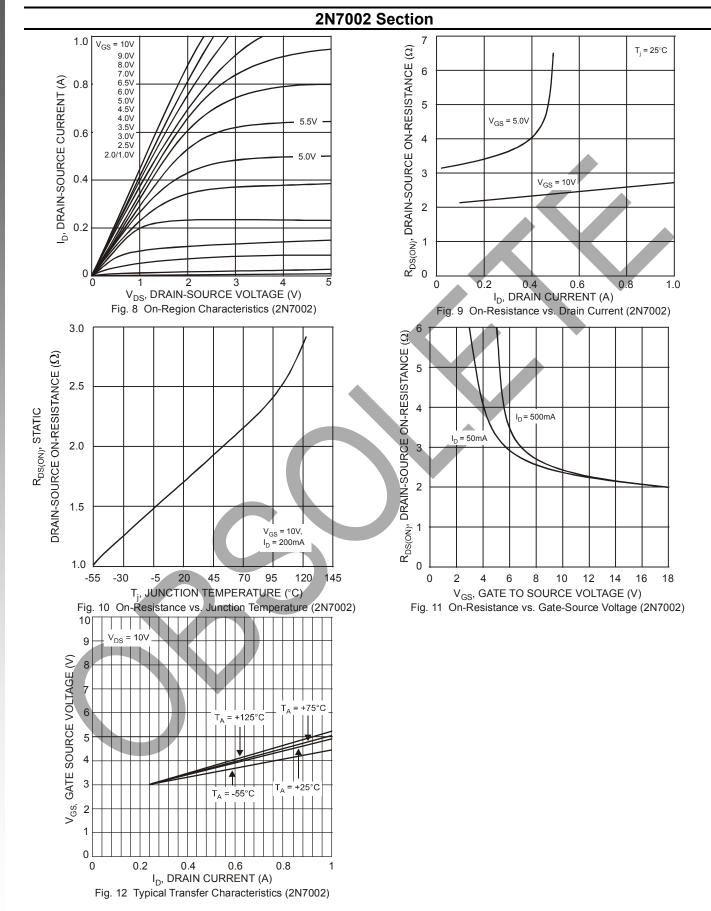


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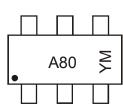


Ordering Information (Note 6)

Device	Packaging	Shipping			
CTA2P1N-7-F	SOT-363	3000/Tape & Reel			

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



A80 = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Date Code Rey												
Year	2004	20	005	2006	5 2007		08	2009 2010		20	11	2012
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Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
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